

SILICON PLANAR VARIABLE CAPACITANCE DOUBLE DIODES

The BB204B and BB204G are double diodes with common cathode in a plastic TO-92 variant, primarily intended for electronic tuning in band II (f.m.). They are recommended for stages where large signals occur (e.g. oscillator circuits).

QUICK REFERENCE DATA

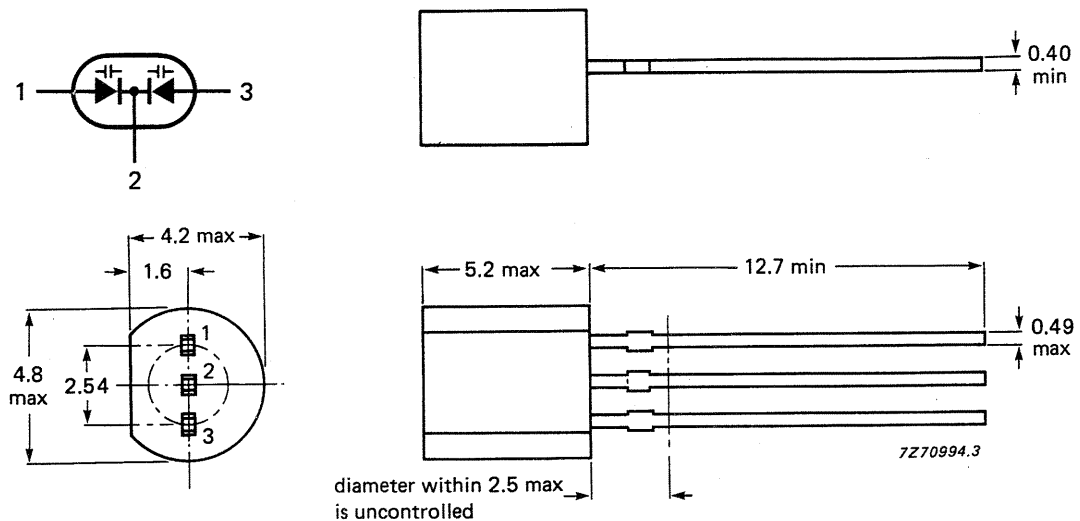
For each diode:

Continuous reverse voltage	V_R	max.	30 V	
Junction temperature	T_j	max.	100 °C	
Reverse current at $V_R = 30$ V	I_R	<	50 nA	
Diode capacitance at $f = 1$ MHz	C_d		BB204G	BB204B
			34 – 39	37 – 42 pF
$V_R = 3$ V	C_d		22 – 27	24 – 29 pF
$V_R = 8$ V			2,5 to 2,8	
Capacitance ratio at $f = 1$ MHz	$\frac{C_d(V_R = 3\text{ V})}{C_d(V_R = 30\text{ V})}$		2,5 to 2,8	
Series resistance at $f = 100$ MHz	r_D	typ.	0,2	Ω
		<	0,4	Ω

MECHANICAL DATA

Dimensions in mm

Fig. 1 TO-92 variant.



BB204B BB204G

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

For each diode:

Continuous reverse voltage	V_R	max.	30 V
Forward current (d.c.)	I_F	max.	100 mA
Storage temperature	T_{stg}		-55 to +100 °C
Junction temperature	T_j	max.	100 °C

CHARACTERISTICS

For each diode:

$T_j = 25\text{ °C}$

Reverse current at $V_R = 30\text{ V}$ $I_R < 50\text{ nA}$

Diode capacitance at $f = 1\text{ MHz}$

$V_R = 3\text{ V}$

	BB204G	BB204B
C_d	34 – 39	37 – 42 pF
C_d	22 – 27	24 – 29 pF
C_d typ.	14 pF	

$V_R = 8\text{ V}$

$V_R = 30\text{ V}$

Capacitance ratio at $f = 1\text{ MHz}$

$\frac{C_d(V_R = 3\text{ V})}{C_d(V_R = 30\text{ V})}$ 2,5 to 2,8

Series resistance at $f = 100\text{ MHz}$

V_R is that value at which $C_d = 38\text{ pF}$

r_D	typ.	0,2	Ω
	<	0,4	Ω

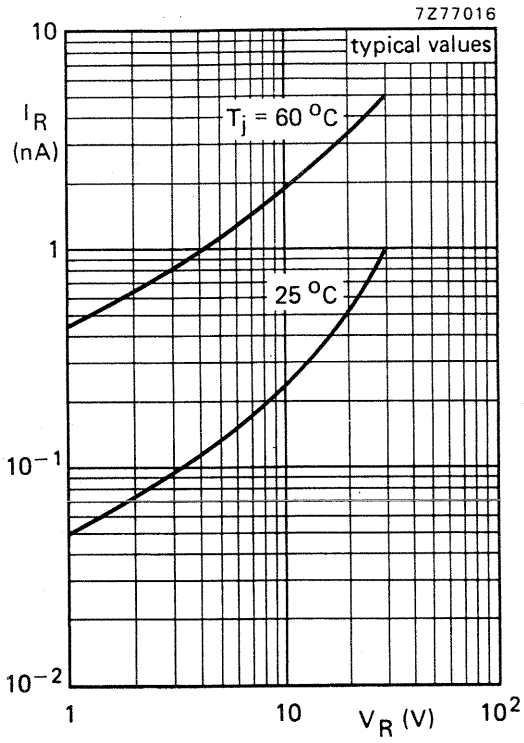


Fig. 2.

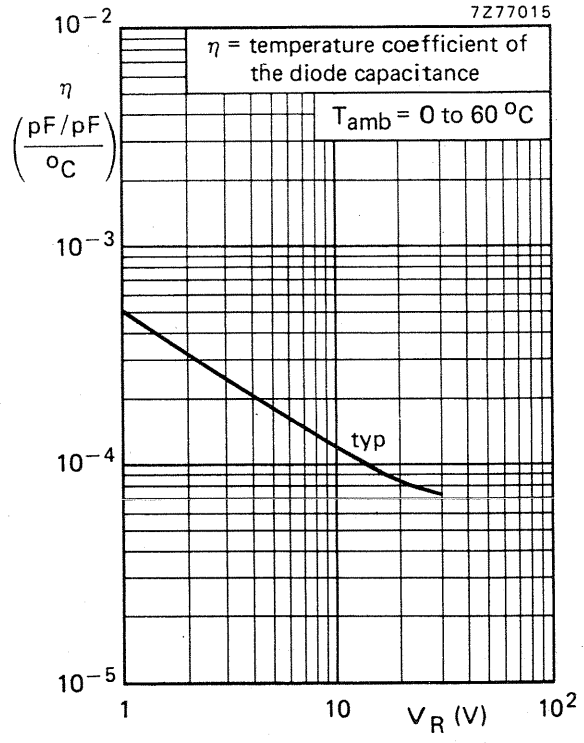


Fig. 3.

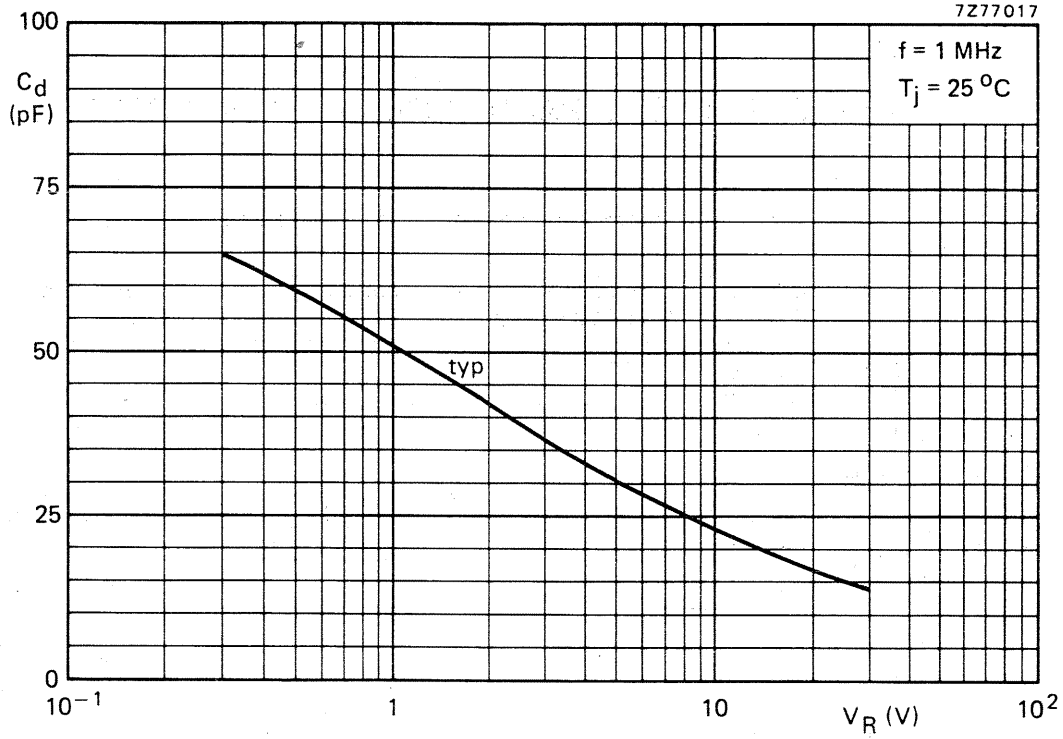


Fig. 4.

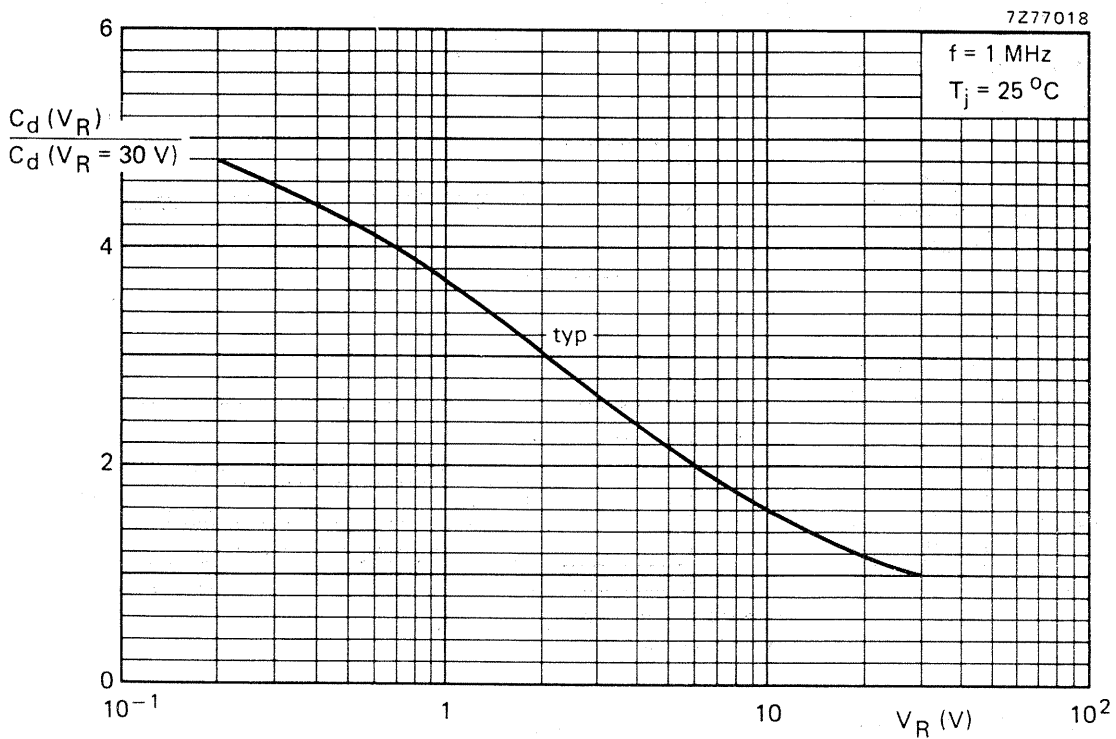


Fig. 5.